

Modeling and Simulation of Ultraviolet Downshifting and Infrared Reflective Encapsulants for Photovoltaic Modules

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Motivations & goals

Motivations [1]

- Improve power conversion efficiency
- Enhance lifetime stability

Target solar module

- Solar cell: c-Si n-type TOPCon
- Configuration: bifacial (glass-glass)
- Efficiency: 23%

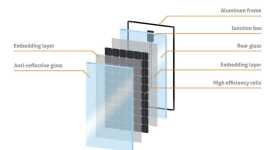


Figure 1 Structure of bifacial PV module

New layers

- Ultraviolet downshifting front encapsulant (UVDS)
- Infrared reflective back encapsulant (IR-reflective)

Goals

Propose experimental, analytical, simulation methods to characterize the impact of such layers on the PV module's performance.

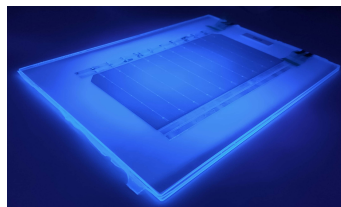


Figure 2 Photo of a mini-module with UVDS layer under artificial UV light

Theory & Methods

Working principles

UV downshifting front encapsulant (UVDS):

- absorbs harmful UV photons → protects from UV degradation
- re-emits blue spectral range photons → generates more electricity

IR reflective back encapsulant (IR-reflective):

- redirects IR light back toward the cell → generates more electricity

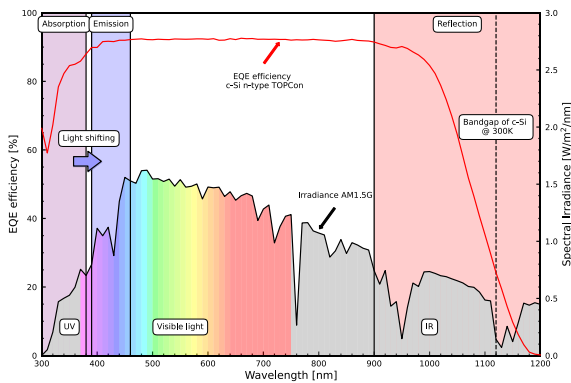


Figure 3 Scheme of UVDS and IR-reflective layers effects on the solar cell's performance

Experimental method

- EQE measurements
- IV-curve measurements
- Spectrophotometry measurements



Analytical method

- Simulate UVDS effect [2,3]
- One-diode electrical model
- Shockley-Queisser thermal model [4]



Simulation method

CROWM

- UVDS and IR-reflective effects simulation
- Combined Ray Optics/Wave optics Model
- New version developed on CROWM [5]

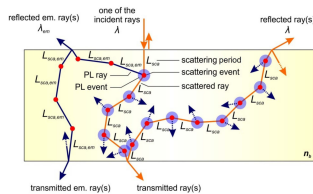


Figure 4 Photoluminescence path scheme

Results

Impact on electrical performance

KPI: short-circuit current density J_{sc}

Optimisation at standard test conditions (STC)

UVDS layer:

Comparison with UV blocker layer

Modification of properties:

- Absorbance scaling factor Λ_{abs}
- Conversion efficiency η_{LDS}

Maximum of +2.6% relative increase

IR-reflective layer:

Comparison with clear matrix layer

Mitigated results

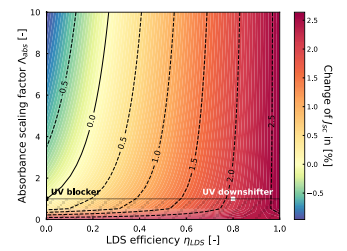


Figure 5 Optimisation color plot for UVDS layer

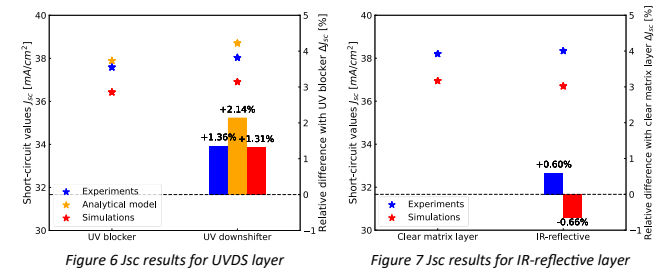


Figure 6 J_{sc} results for UVDS layer

Figure 7 J_{sc} results for IR-reflective layer

Impact on energy yield

Different weather conditions days for UVDS layer

- Clear sky summer day
- Cloudy sky summer day
- Clear sky winter day
- Cloudy sky winter day

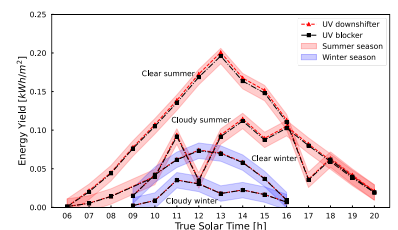


Figure 8 Energy yield estimation per hours

Yearly increase: +2.18%

Day	Clear summer	Cloudy summer	Clear winter	Cloudy winter	Year
Absolute gain [Wh/m²]	+34.74	+21.16	+3.69	+1.44	+2'804
Relative gain [%]	+2.62%	+2.73%	+1.01%	+1.03%	+2.18%

Figure 9 Energy yield results with UVDS layer

Conclusion & perspectives

- UV downshifting front encapsulant can enhance the energy yield by +2%.
- IR-reflective back encapsulant shows mitigated results.
- New version of CROWM with photoluminescence incorporation.
- Broader applications could benefit from the UV downshifting effect.

Acknowledgements

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References

- [1] Mark Hutchins, "Solving the UV Problem of N-Type Solar", in: pv magazine International (Oct. 18, 2024), url: https://www.pv-magazine.com/2024/10/18/solving-the-uv-problem-of-n-type-solar/.
- [2] Ahmed M. Gaber et al., "Modeling Down-Conversion and Down-Shifting for Photovoltaic Applications", in: 2012 38th IEEE Photovoltaic Specialists Conference, 2012, pp. 48-52, doi: 10.1109/PVSC.2012.6317466.
- [3] R. Rothemann, "Optical Modeling of the External Quantum Efficiency of Solar Cells with Luminescent Down-Shifting Layers", in: Solar Energy Materials and Solar Cells 120 (2014), pp. 616-621, doi: 10.1016/j.solmat.2013.10.004.
- [4] Méline Dumoulin, "Refractoisement radiatif des cellules et modules solaires par structuration de surface", Thèse de doctorat, Université de Lyon: INSA Lyon, 2023, url: https://theses.insa-lyon.fr/publication/2023ISA00005/these.pdf.
- [5] Benjamin Lipovšek et al., "Optical Model for Simulation and Optimization of Luminescent Down-Shifting Layers in Photovoltaics", in: Energy Procedia 84 (2015), pp. 3-7, doi: 10.1016/j.egypro.2015.12.288.